

54H30

8-Input Positive-NAND Gates

These devices contain a single 8-input NAND gate.

They are characterized for operation over the full military range of -55°C to 125°C.

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer (OCM).

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
 - Class Q Military
 - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
 - Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

FOR REFERENCE ONLY

**TYPES SN5430, SN54H30, SN54L30, SN54LS30, SN54S30,
SN7430, SN74H30, SN74LS30, SN74S30
8-INPUT POSITIVE-NAND GATES**

REVISED DECEMBER 1983

- Package Options Include Both Plastic and Ceramic Chip Carriers in Addition to Plastic and Ceramic DIPs
- Dependable Texas Instruments Quality and Reliability

description

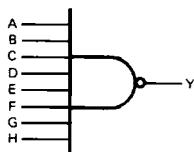
These devices contain a single 8-input NAND gate.

The SN5430, SN54H30, SN54L30, SN54LS30, and SN54S30 are characterized for operation over the full military range of -55°C to 125°C . The SN7430, SN74H30, SN74LS30, and SN74S30 are characterized for operation from 0°C to 70°C .

FUNCTION TABLE

INPUTS A THRU H	OUTPUT Y
All inputs H	L
One or more inputs L	H

logic diagram



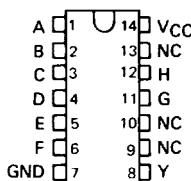
positive logic

$$Y = \overline{A \cdot B \cdot C \cdot D \cdot E \cdot F \cdot G \cdot H} \quad \text{or}$$

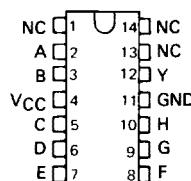
$$Y = \overline{A} + \overline{B} + \overline{C} + \overline{D} + \overline{E} + \overline{F} + \overline{G} + \overline{H}$$

SN5430, SN54H30, SN54L30 ... J PACKAGE
SN54LS30, SN54S30 ... J OR W PACKAGE
SN7430, SN74H30 ... J OR N PACKAGE
SN74LS30, SN74S30 ... D, J OR N PACKAGE

(TOP VIEW)

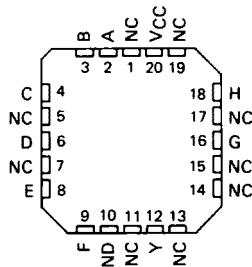


SN5430, SN54H30 ... W PACKAGE
(TOP VIEW)



SN54LS30, SN54S30 ... FK PACKAGE
SN74LS30, SN74S30 ... FN PACKAGE

(TOP VIEW)



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TTL DEVICES

NC - No internal connection

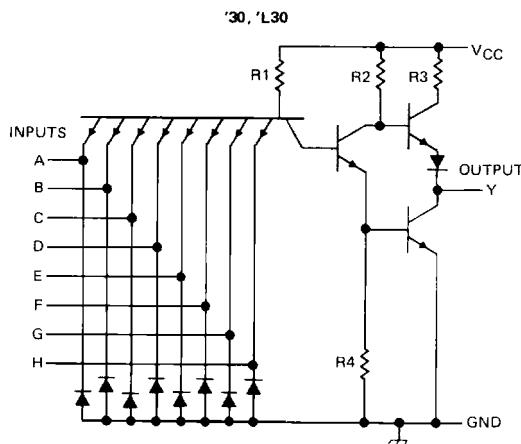
PRODUCTION DATA
This document contains information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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**TYPES SN5430, SN54H30, SN54L30,
SN7430, SN74H30
8-INPUT POSITIVE-NAND GATES**

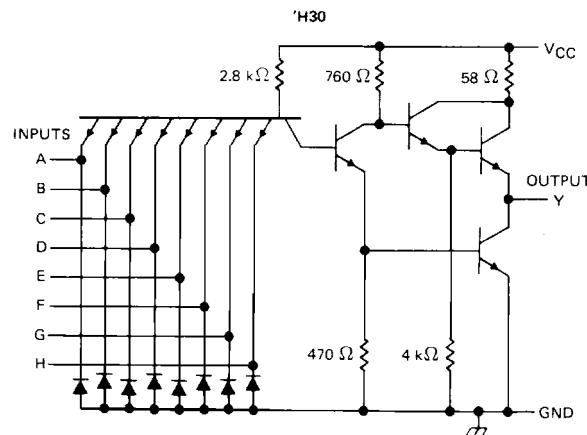
schematics (each gate)



CIRCUIT	R1	R2	R3	R4
'30	4 kΩ	1.6 kΩ	130 Ω	1 kΩ
'L30	40 kΩ	20 kΩ	500 Ω	12 kΩ

Input clamp diodes not on SN54L30 circuit.

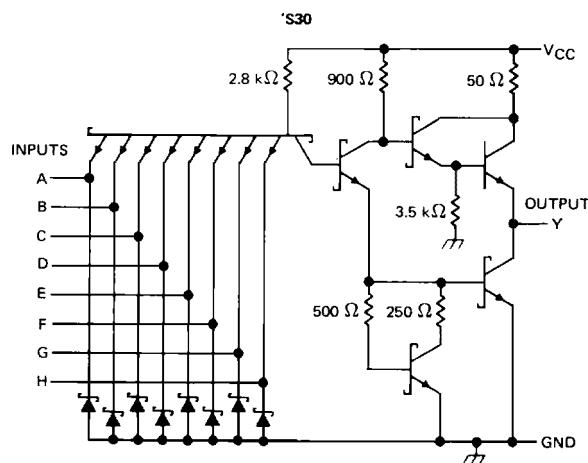
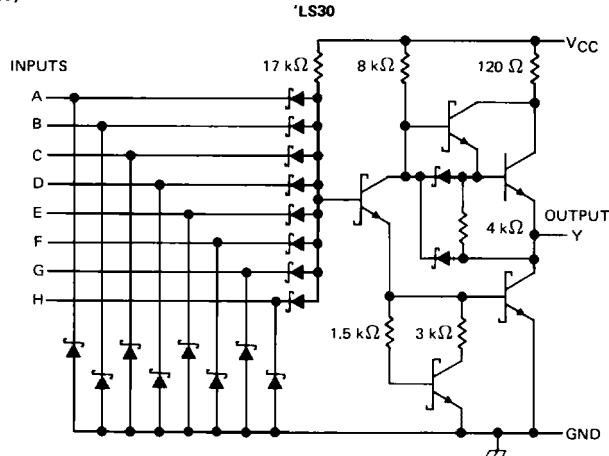
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Resistor values shown are nominal.

**TYPES SN5430, SN54H30, SN54L30, SN54LS30, SN54S30,
SN7430, SN74H30, SN74LS30, SN74S30
8-INPUT POSITIVE-NAND GATES**

schematics (each gate)



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TTL DEVICES

Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1): '30, 'H30, 'LS30, 'S30	7 V
'L30	8 V
Input voltage: '30, 'H30, 'L30, 'S30	5.5 V
'LS30	7 V
Operating free-air temperature: SN54'	-55°C to 125°C
SN74'	0°C to 70°C
Storage temperature range	-65°C to 150°C

NOTE 1: Voltage values are with respect to network ground terminal.

**TEXAS
INSTRUMENTS**

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TYPES SN5430, SN7430 8-INPUT POSITIVE-NAND GATES

recommended operating conditions

		SN5430			SN7430			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High-level input voltage	2			2			V
V _{IL}	Low-level input voltage			0.8			0.8	V
I _{OH}	High-level output current			-0.4			-0.4	mA
I _{OL}	Low-level output current			16			16	mA
T _A	Operating free-air temperature	-55	125	0	70			°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS†	SN5430			SN7430			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -12 mA			-1.5			-1.5	V
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = -0.4 mA	2.4	3.4		2.4	3.4		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 16 mA	0.2	0.4		0.2	0.4		V
I _I	V _{CC} = MAX, V _I = 5.5 V			1			1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.4 V			40			40	µA
I _{IL}	V _{CC} = MAX, V _I = 0.4 V			-1.6			-1.6	mA
I _{OS§}	V _{CC} = MAX	-20	-55		-18		-55	mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V	1	2		1	2		mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V	3	6		3	6		mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

§ Not more than one output should be shorted at a time.

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TTL DEVICES

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 400 Ω, C _L = 15 pF	13	22		ns
				8	15		ns

NOTE 2: See General Information Section for load circuits and voltage waveforms.

**TYPES SN54H30, SN74H30
8-INPUT POSITIVE-NAND GATES**

recommended operating conditions

		SN54H30			SN74H30			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High-level input voltage		2		2			V
V _{IL}	Low-level input voltage			0.8		0.8		V
I _{OH}	High-level output current			-0.5		-0.5		mA
I _{OL}	Low-level output current			20		20		mA
T _A	Operating free-air temperature	-55	125	0	70			°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †			MIN	TYP‡	MAX	UNIT
	V _{IK}	V _{CC} = MIN, I _I = -8 mA			-	1.5	V
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = -0.5 mA			2.4	3.5		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 20 mA			0.2	0.4		V
I _I	V _{CC} = MAX, V _I = 5.5 V				1		mA
I _{IH}	V _{CC} = MAX, V _I = 2.4 V				50		µA
I _{IL}	V _{CC} = MAX, V _I = 0.4 V				-2		mA
I _{OS\$}	V _{CC} = MAX			-40	-100		mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V			2.5	4.2		mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V			6.5	10		mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

\$ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM	TO	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	(INPUT)	(OUTPUT)					
t _{PLH}	Any	Y	R _L = 280 Ω, C _L = 25 pF	6.8	10		ns
t _{PHL}				8.9	12		ns

NOTE 2: See General Information Section for load circuits and voltage waveforms.

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TYPE SN54L30

8-INPUT POSITIVE-NAND GATES

recommended operating conditions

		SN54L30			UNIT
		MIN	NOM	MAX	
V _{CC}	Supply voltage	4.5	5	5.5	V
V _{IH}	High-level input voltage	2			V
V _{IL}	Low-level input voltage			0.7	V
I _{OH}	High-level output current			-0.1	mA
I _{OL}	Low-level output current			2	mA
T _A	Operating free-air temperature	-55		125	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54L30			UNIT
		MIN	TYP‡	MAX	
V _{OH}	V _{CC} = MIN, V _{IL} = 0.7 V, I _{OH} = -0.1 mA	2.4	3.3		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 2 mA	0.15	0.3		V
I _I	V _{CC} = MAX, V _I = 5.5 V			0.1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.4 V			10	μA
I _{IL}	V _{CC} = MAX, V _I = 0.3 V			-0.18	mA
I _{OS\$}	V _{CC} = MAX	-3		-15	mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V	0.11	0.33		mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V	0.29	0.51		mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

\$ Not more than one output should be shorted at a time.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 4 kΩ, C _L = 50 pF	35	60		ns
t _{PHL}				70	100		ns

NOTE 2: See General Information Section for load circuits and voltage waveforms.

TYPES SN54LS30, SN74LS30 8-INPUT POSITIVE-NAND GATES

recommended operating conditions

		SN54LS30			SN74LS30			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH}	High-level input voltage	2			2			V
V _{IL}	Low-level input voltage			0.7			0.8	V
I _{OH}	High-level output current			-0.4			-0.4	mA
I _{OL}	Low-level output current			4			8	mA
T _A	Operating free-air temperature	-55		125	0		70	°C

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54LS30			SN74LS30			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -18 mA			-1.5			-1.5	V
V _{OH}	V _{CC} = MIN, V _I = MAX, I _{OH} = -0.4 mA	2.5	3.4		2.7	3.4		V
V _{OL}	V _{CC} = MIN, V _I = 2 V, I _{OL} = 4 mA		0.25	0.4		0.4		V
	V _{CC} = MIN, V _I = 2 V, I _{OL} = 8 mA				0.25	0.5		
I _I	V _{CC} = MAX, V _I = 7 V			0.1			0.1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.7 V			20			20	μA
I _{IL}	V _{CC} = MAX, V _I = 0.4 V			-0.4			-0.4	mA
I _{OS} §	V _{CC} = MAX	-20	-100		-20	-100		mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V	0.35	0.5		0.35	0.5		mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V	0.6	1.1		0.6	1.1		mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C

§ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 2 kΩ, C _L = 15 pF	8	15		ns
t _{PHL}				13	20		ns

NOTE 2: See General Information Section for load circuits and voltage waveforms

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TTL DEVICES

TYPES SN54S30, SN74S30 8-INPUT POSITIVE-NAND GATES

recommended operating conditions

	SN54S30			SN74S30			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC} Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V _{IH} High-level input voltage	2			2			V
V _{IL} Low-level input voltage				0.8		0.8	V
I _{OH} High-level output current				-1		-1	mA
I _{OL} Low-level output current				20		20	mA
T _A Operating free-air temperature	-55	125	0	0	70	0°C	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS †	SN54S30			SN74S30			UNIT
		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V _{IK}	V _{CC} = MIN, I _I = -18 mA			-1.2			-1.2	V
V _{OH}	V _{CC} = MIN, V _{IL} = 0.8 V, I _{OH} = -1 mA	2.5	3.4		2.7	3.4		V
V _{OL}	V _{CC} = MIN, V _{IH} = 2 V, I _{OL} = 20 mA			0.5			0.5	V
I _I	V _{CC} = MAX, V _I = 5.5 V			1			1	mA
I _{IH}	V _{CC} = MAX, V _I = 2.7 V			50			50	μA
I _{IL}	V _{CC} = MAX, V _I = 0.5 V			-2			-2	mA
I _{OS\$}	V _{CC} = MAX	-40	-100		-40	-100		mA
I _{CCH}	V _{CC} = MAX, V _I = 0 V		3	5		3	5	mA
I _{CCL}	V _{CC} = MAX, V _I = 4.5 V		5.5	10		5.5	10	mA

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.

\$ Not more than one output should be shorted at a time, and the duration of the short-circuit should not exceed one second.

switching characteristics, V_{CC} = 5 V, T_A = 25°C (see note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{PLH}	Any	Y	R _L = 280 Ω, C _L = 15 pF	4	6		ns
t _{PHL}				4.5	7		ns
t _{PLH}		Y	R _L = 280 Ω, C _L = 50 pF	5.5			ns
t _{PHL}				6.5			ns

NOTE 2: See General Information Section for load circuits and voltage waveforms.



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